

Subject card

Subject name and code	Electronics, PG_00039882								
Field of study	Mechanical Engineering, Mechanical Engineering								
Date of commencement of studies	October 2020		Academic year of realisation of subject			2021/2022			
Education level	first-cycle studies		Subject group			Obligatory subject group in the field of study			
Mode of study	Full-time studies		Mode of delivery			at the university			
Year of study	2		Language of instruction			Polish			
Semester of study	4		ECTS credits			2.0			
Learning profile	general academic profile		Assessment form			assessment			
Conducting unit	Department of Microelectronic Systems -> Faculty of Electronics, Telecommunications and Informatics								
Name and surname of lecturer (lecturers)	Subject supervisor		dr hab. inż. Wiesław Kordalski						
	Teachers		dr hab. inż. Wiesław Kordalski						
Lesson types and methods of instruction	Lesson type	Lecture	Tutorial	Laboratory	Projec	t	Seminar	SUM	
	Number of study hours	15.0	0.0	15.0	0.0		0.0	30	
	E-learning hours included: 0.0								
	Adresy na platformie eNauczanie:								
Learning activity and number of study hours	Learning activity	Participation in classes include plan			Self-study SUM		SUM		
	Number of study hours	30		5.0		15.0		50	
Subject objectives	The aim is to present fundamentals of electrical engineering.								
Learning outcomes	Course outcome		Subject outcome			Method of verification			
	[K6_W10] possesses basic knowledge on electronics and electrical engineering		Student has an elementary knowledge of electrical engineering and electronics. Student explains principles of operation of basic electronic circuits such as rectifiers and elctronic amplifiers.			[SW1] Assessment of factual knowledge			
	[K6_U05] is able to plant an experiment within the range of measuring the basic operating parameters of mechanical devices using a specialized equipment, interpret the results and reach the correct conclusions		The student is able to find the necessary information in professional literature, databases and other sources to measure the basic parameters of mechanical devices. The student is able to interpret the measurement results and draw conclusions.			[SU3] Assessment of ability to use knowledge gained from the subject [SU1] Assessment of task fulfilment [SU2] Assessment of ability to analyse information			

Data wydruku: 19.04.2024 20:41 Strona 1 z 2

1. Semiconductors in electronics: electronic conductivity, piezo-, photo- and magnetoresistivity, Hall affect. 2. Semiconductor sensors: piezoresistors, thermistors, photoresistors gaussofrons, Hall sensor, pressure and gas sensors. 3. Semiconductor diodes and their applications. 4. Bipolar and field effect transistors: current-voltage characteristics and amplyfing capabilities. 5. Microelectromechanical systems (MEMS). 6. Rectifiers and suppliers. 7. Spectrum of periodic and nonperiodic electronic signals; linear and nonlinear signal distortions in electronic ricinis. 8. Signal amplifying. Operational amplifiers and voltage comparators: 9. Sine wave generators. Relaxation oscillators and multivibrators. 10. Digital representation of analogy signal: sampling, qualization, coding and Nyquist theorem. 11. Combinational and sequential digital circuits. Laboratory list of topics: 1. Introductory remarks. 2. Measurements of static characteristics of selected semiconductor diodes. 3. Current- voltage characteristics of Zener diodes. 4. Measurements of a input stage of an operational amplifiers. 5. Nepolar transistor basic configurations of operational amplifiers. 6. Nepolarise. 7 Ripolar transistor basic configurations of operation. 8. MOS transistor basic configurations of operation. 9. Power amplifier. 6. Nepolarise feedback in amplifiers. 7. Bipolar transistor basic configurations of operation. 8. MOS transistor basic configurations of operation. 9. Power amplifier. 9. Nepolarise feedback in amplifiers. 7. Bipolar transistor basic configurations of operation. 9. Power amplifier. 9. Nepolarise feedback in amplifiers. 7. Bipolar transistor basic configurations of operation. 9. Power amplifier. 9. Nepolarise feedback in particular of the final grade transistor and configurations of operation. 9. Power amplifier. 9. Nepolarise feedback in particular feedback provided to the final grade feedback in particular feedback provided feedback in particular feedback provided feedback in particular feedback provided feedback	Subject contents	Lecture list of topics							
2. Semiconductor sensors: plezoresistors, thermistors, photoresistors, gaussortons, Hall sensor, pressure and gas sensors. 3. Semiconductor clicides and their applications. 4. Bipolar and field effect transistors: current-voltage characteristics and amplyfing capabilities. 5. Microelectromechanical systems (MEMS). 6. Rectifiers and suspilers. 7. Spectrum of percoid and nonperiodic electronic applications is respectively. 9. Sine wave generators. Relacation ascillators and multiwibration. 16. Digital representation of analog signal: sampling, qualitzation, coding and Nyquist theorem. 11. Combinational and sequential digital circuits. 1. Introductory remarks. 2. Measurements of static characteristics of selected semiconductor diodes. 3. Current- voltage characteristics of Zener diodes. 4. Measurements of a input stage of an operational amplifier. 5. Selected applications of operational amplifiers. 6. Negative feedback in amplifiers. 7. Bipolar transistor basic configurations of operation. 8. MOS transistor basic configurations of operation. 8. MOS transistor basic configurations of operation. 9. Power amplifier. 10. Amplifier with resonance circuits. Prerequisites no prerequisites no prerequisites. 1. Introductory remarks. 2. Measurements of static characteristics of selected semiconductor diodes. 3. MOS transistor basic configurations of operational amplifiers. 6. Negative feedback in amplifiers. 7. Bipolar transistor basic configurations of operation. 8. MOS transistor basic configurations of operations. 8. MOS transistor basic configurations. 9. Power amplifier. 9. Power amplifier. 9. Power amplifier. 9. Power	oubject contents	200taro not or topioo							
1. Introductory remarks, 2. Measurements of static characteristics of selected semiconductor diodes. 3. Current- voltage characteristics of Zener diodes. 4. Measurements of a input stage of an operational amplifier. 5. Selected applications of operation all amplifiers. 6. Negative feedback in amplifiers, 7. Bipolar transistor basic configurations of operation. 8. MOS transistor basic configurations of operation. 9. Power amplifier. 10. Amplifier with resonance circuits. Prerequisites and co-requisites and criteria Subject passing criteria Passing threshold Percentage of the final grade		Semiconductor sensors: piezoresistors, thermistors, photoresistors, gaussotrons, Hall sensor, pressure and gas sensors. Semiconductor diodes and their applications. Semiconductors: S							
3. Current-voltage characteristics of Zener diodes. 4. Measurements of a input stage of an operational amplifiers. 5. Selected applications of operational amplifiers. 5. Selected applications of operation. 8. MOS transistor basic configurations of operation. 9. Power amplifier. 10. Amplifier with resonance circuits. Prerequisites no prerequisites. Subject passing criteria Subject passing criteria Lecture - test written at the end of a term. Laboratory - reports of practical exercises. Recommended reading Basic literature 1. J. Watson: Elektronika, WKiŁ, 2002. 2. P. Horowitz i W. Hill: Sztuka elektroniki, WKiŁ, 1996. 3. M. Polowczyk , A. Jurewicz: Elektronika dla Mechaników, Wyd. PG, 2002. Supplementary literature 1. A. Sedra and K. C Smith: Microelectronic circuits, Oxford, 2007. 2. J. Osiowski, J. Szabatin: Podstawy teorii obwodów, t.2, WNT. 3. M. Polowczyk , E. Klugmann: Przyrządy półprzwodnikowe, Wyd. PG, 1996. Example issues/ example questions/ tasks being completed		Laboratory list of topics:							
Assessment methods and criteria Subject passing criteria Passing threshold Percentage of the final grade		3. Current- voltage characteristics of Zener diodes. 4. Measurements of a input stage of an operational amplifier. 5. Selected applications of operational amplifiers. 6. Negative feedback in amplifiers. 7. Bipolar transistor basic configurations of operation. 8. MOS transistor basic configurations of operation. 9. Power							
and criteria Lecture - test written at the end of a term. 50.0% 50.0% 50.0%		no prerequisites.							
Recommended reading Basic literature 1. J. Watson: Elektronika, WKiŁ, 2002. 2. P. Horowitz i W. Hill: Sztuka elektroniki, WKiŁ, 1996. 3. M. Polowczyk, A. Jurewicz: Elektronika dla Mechaników, Wyd. PG, 2002. Supplementary literature 1. A. Sedra and K. C Smith: Microelectronic circuits, Oxford, 2007. 2. J. Osiowski, J. Szabatin: Podstawy teorii obwodów, t.2, WNT. 3. M. Polowczyk, E. Klugmann: Przyrządy półprzwodnikowe, Wyd. PG, 1996. eResources addresses Draw common-emitter output characetistics for an n-p-n bipolar transistor and define the normal common-emitter current gain (beta) and the normal common-base current gain (alpha).		Subject passing criteria	Passing threshold	Percentage of the final grade					
Recommended reading Basic literature 1. J. Watson: Elektronika, WKiŁ, 2002. 2. P. Horowitz i W. Hill: Sztuka elektroniki, WKiŁ, 1996. 3. M. Polowczyk , A. Jurewicz: Elektronika dla Mechaników, Wyd. PG, 2002. Supplementary literature 1. A. Sedra and K. C Smith: Microelectronic circuits, Oxford, 2007. 2. J. Osiowski, J. Szabatin: Podstawy teorii obwodów, t.2, WNT. 3. M. Polowczyk , E. Klugmann: Przyrządy półprzwodnikowe, Wyd. PG, 1996. Example issues/ example questions/ tasks being completed Draw common-emitter output characetistics for an n-p-n bipolar transistor and define the normal common-emitter current gain (beta) and the normal common-base current gain (alpha).			50.0%	50.0%					
2. P. Horowitz i W. Hill: Sztuka elektroniki, WKiŁ, 1996. 3. M. Polowczyk , A. Jurewicz: Elektronika dla Mechaników, Wyd. PG, 2002. Supplementary literature 1. A. Sedra and K. C Smith: Microelectronic circuits, Oxford, 2007. 2. J. Osiowski, J. Szabatin: Podstawy teorii obwodów, t.2, WNT. 3. M. Polowczyk , E. Klugmann: Przyrządy półprzwodnikowe, Wyd. PG, 1996. eResources addresses Example issues/ example questions/ tasks being completed			50.0%	50.0%					
3. M. Polowczyk , A. Jurewicz: Elektronika dla Mechaników, Wyd. PG, 2002. Supplementary literature 1. A. Sedra and K. C Smith: Microelectronic circuits, Oxford, 2007. 2. J. Osiowski, J. Szabatin: Podstawy teorii obwodów, t.2, WNT. 3. M. Polowczyk , E. Klugmann: Przyrządy półprzwodnikowe, Wyd. PG, 1996. eResources addresses Example issues/ example questions/ tasks being completed	Recommended reading	Basic literature	002.						
Supplementary literature 1. A. Sedra and K. C Smith: Microelectronic circuits, Oxford, 2007. 2. J. Osiowski, J. Szabatin: Podstawy teorii obwodów, t.2, WNT. 3. M. Polowczyk, E. Klugmann: Przyrządy półprzwodnikowe, Wyd. PG, 1996. eResources addresses Example issues/ example questions/ tasks being completed Draw common-emitter output characetistics for an n-p-n bipolar transistor and define the normal common-emitter current gain (beta) and the normal common-base current gain (alpha).			3. M. Polowczyk , A. Jurewicz: Elektronika dla Mechaników, Wyd. PG,						
2. J. Osiowski, J. Szabatin: <i>Podstawy teorii obwodów</i> , t.2, WNT. 3. M. Polowczyk , E. Klugmann: Przyrządy półprzwodnikowe, Wyd. PG, 1996. eResources addresses Example issues/ example questions/ tasks being completed Draw common-emitter output characetistics for an n-p-n bipolar transistor and define the normal common-emitter current gain (beta) and the normal common-base current gain (alpha).			2002.						
3. M. Polowczyk , E. Klugmann: Przyrządy półprzwodnikowe, Wyd. PG, 1996. eResources addresses Example issues/ example questions/ tasks being completed Draw common-emitter output characetistics for an n-p-n bipolar transistor and define the normal common-emitter current gain (beta) and the normal common-base current gain (alpha).		Supplementary literature 1. A. Sedra and K. C Smith: <i>Microelectronic circuits</i> , Oxford, 2007							
eResources addresses Example issues/ example questions/ tasks being completed EResources addresses Draw common-emitter output characetistics for an n-p-n bipolar transistor and define the normal common-emitter current gain (beta) and the normal common-base current gain (alpha).			2. J. Osiowski, J. Szabatin: <i>Podstawy teorii obwodów</i> , t.2, WNT.						
Example issues/ example questions/ tasks being completed Draw common-emitter output characetistics for an n-p-n bipolar transistor and define the normal common-emitter output characetistics for an n-p-n bipolar transistor and define the normal common-emitter output characetistics for an n-p-n bipolar transistor and define the normal common-emitter output characetistics for an n-p-n bipolar transistor and define the normal common-emitter output characetistics for an n-p-n bipolar transistor and define the normal common-emitter output characetistics for an n-p-n bipolar transistor and define the normal common-emitter output characetistics for an n-p-n bipolar transistor and define the normal common-emitter output characetistics for an n-p-n bipolar transistor and define the normal common-emitter output characetistics for an n-p-n bipolar transistor and define the normal common-emitter output characetistics for an n-p-n bipolar transistor and define the normal common-emitter output characetistics for an n-p-n bipolar transistor and define the normal common-base current gain (alpha).				wczyk , E. Klugmann: Przyrządy półprzwodnikowe, Wyd. PG,					
example questions/ emitter current gain (beta) and the normal common-base current gain (alpha). tasks being completed		eResources addresses							
	example questions/								
Work placement Not applicable	Work placement	Not applicable	Not applicable						

Data wydruku: 19.04.2024 20:41 Strona 2 z 2